

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Plastic Medium-Power Complementary Silicon Transistors

These devices are designed for general-purpose amplifier and low-speed switching applications.



• High DC Current Gain -

 $h_{FE} = 2500 \text{ (Typ) } @ I_C = 4.0 \text{ Adc}$

• Collector Emitter Sustaining Voltage – @ 100 mAdc

 $V_{CEO(sus)} = 80 \text{ Vdc (Min)} - BDX53B, 54B$ = 100 Vdc (Min) - BDX53C, 54C

• Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 2.0 \text{ Vdc (Max)} @ I_C = 3.0 \text{ Adc}$ = 4.0 Vdc (Max) @ I_C = 5.0 Adc

- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BDX53B, BDX54B BDX53C, BDX54C	V _{CEO}	80 100	Vdc
Collector-Base Voltage BDX53B, BDX54B BDX53C, BDX54C	V _{CB}	80 100	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous – Peak	I _C	8.0 12	Adc
Base Current	I _B	0.2	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	65 0.48	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	70	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.92	°C/W



ON Semiconductor®

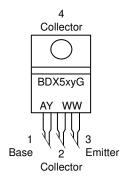
www.onsemi.com

DARLINGTON 8 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80–100 VOLTS, 65 WATTS



TO-220 CASE 221A STYLE 1

MARKING DIAGRAM & PIN ASSIGNMENT



BDX5xy = Device Codex = 3 or 4

A = Assembly Location

v = B or C

Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

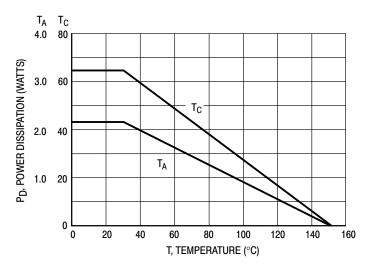


Figure 1. Power Derating

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (Note 1) (I _C = 100 mAdc, I _B = 0)	BDX53B, BDX54B BDX53C, BDX54C	V _{CEO(sus)}	80 100	_ _	Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 50 \text{ Vdc}, I_B = 0)$	BDX53B, BDX54B BDX53C, BDX54C	I _{CEO}	- -	0.5 0.5	mAdc
Collector Cutoff Current $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$	BDX53B, BDX54B BDX53C, BDX54C	I _{CBO}	- -	0.2 0.2	mAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I _C = 3.0 Adc, V _{CE} = 3.0 Vdc)		h _{FE}	750	_	_
Collector–Emitter Saturation Voltage (I _C = 3.0 Adc, I _B = 12 mAdc)		V _{CE(sat)}	- -	2.0 4.0	Vdc
Base–Emitter Saturation Voltage (I _C = 3.0 Adc, I _C = 12 mA)		V _{BE(sat)}	-	2.5	Vdc
DYNAMIC CHARACTERISTICS					
Small-Signal Current Gain (I _C = 3.0 Adc, V _{CE} = 4.0 Vdc, f = 1.0 MHz)		h _{fe}	4.0	_	_
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	BDX53B, 53C BDX54B, 54C	C _{ob}	_ _	300 200	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

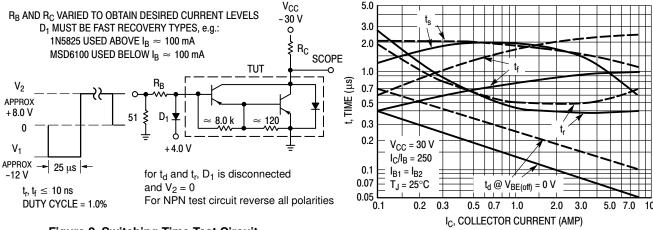


Figure 2. Switching Time Test Circuit

Figure 3. Switching Times

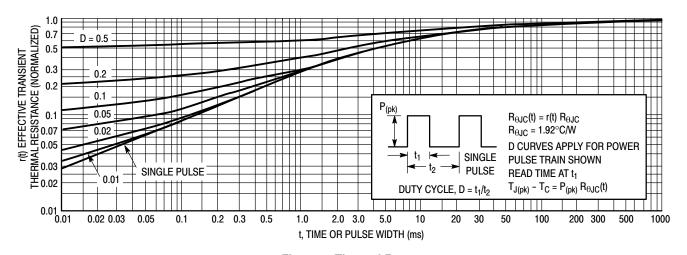


Figure 4. Thermal Response

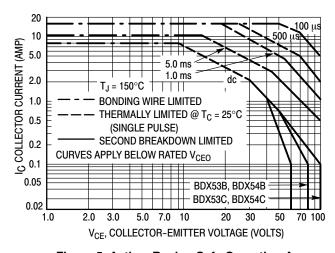


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150$ °C; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150$ °C. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

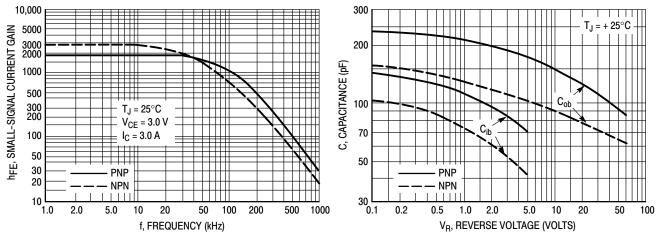


Figure 6. Small-Signal Current Gain

Figure 7. Capacitance

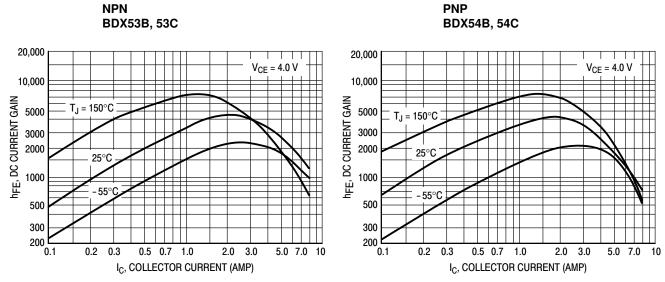


Figure 8. DC Current Gain

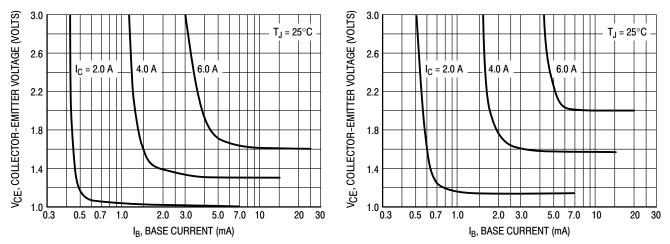


Figure 9. Collector Saturation Region

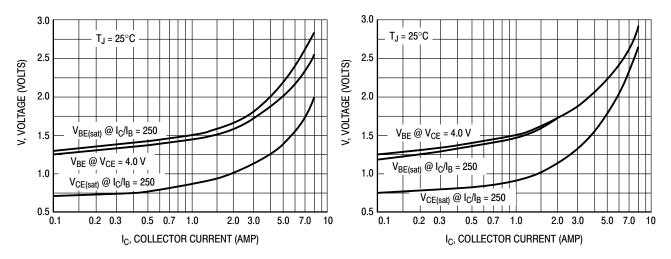


Figure 10. "On" Voltages

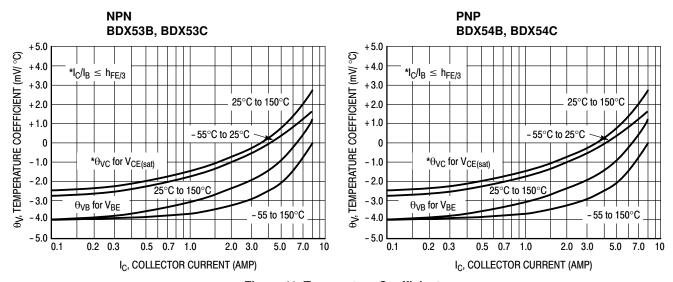


Figure 11. Temperature Coefficients

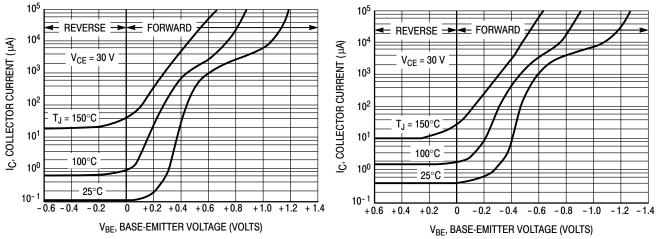
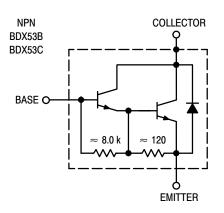


Figure 12. Collector Cut-Off Region



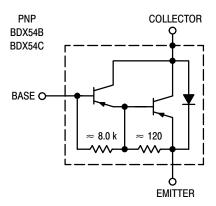


Figure 13. Darlington Schematic

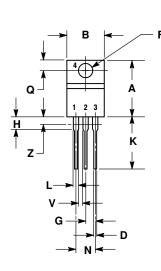
ORDERING INFORMATION

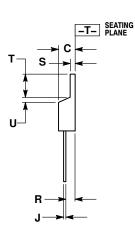
Device	Package	Shipping [†]
BDX53BG	TO-220 (Pb-Free)	50 Units / Rail
BDX53CG	TO-220 (Pb-Free)	50 Units / Rail
BDX54BG	TO-220 (Pb-Free)	50 Units / Rail
BDX54CG	TO-220 (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
٦	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 1:

BASE PIN 1.

COLLECTOR

EMITTER 3 COLLECTOR

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